NSN 5961-01-065-0019

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Inclosure Material:

Metal

Overall Length:

0.260 inches

Overall Diameter:

0.375 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

2.00 amperes source cutoff current

Power Rating Per Characteristic:

4.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

98230-0n225124 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0